## onsemi

### Quad 2-Input Exclusive OR Gate

### **MM74HC86**

The MM74HC86 exclusive OR gate utilizes advanced silicon–gate CMOS technology to achieve operating speeds similar to equivalent LS–TTL gates, while maintaining the low power consumption and high noise immunity characteristic of standard CMOS integrated circuits. These gates are fully buffered and have a fanout of 10 LS–TTL loads. The 74HC logic family is functionally as well as pin–out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $V_{\rm CC}$  and ground.

#### Features

- Typical Propagation Delay: 12 ns
- Wide Operating Voltage Range: 2 V 6 V
- Low Input Current: 1 µA Maximum
- Low Quiescent Current: 40 µA Maximum (74 Series)
- Output Drive Capability: 10 LS-TTL Loads
- These Devices are Pb-Free, Halide Free and are RoHS Compliant

#### **Connection Diagram**

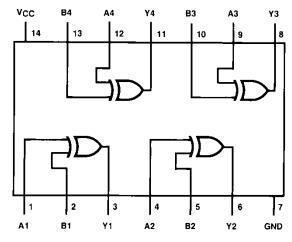
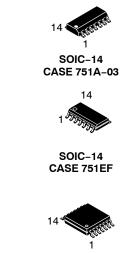


Figure 1. Pin Assignments (Top View)

#### TRUTH TABLE

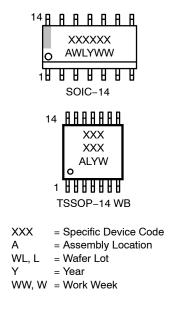
Inp	Outputs	
А	В	Y (Note1)
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

1.  $Y = A \oplus B = \overline{AB} + A\overline{B}$ 



TSSOP-14 CASE 948G

#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

#### MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5	V <sub>CC</sub> + 0.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub> , I <sub>OK</sub>	Clamp Diode Current	±	±20		
I <sub>OUT</sub>	DC Output Current, per Pin	±	±25		
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current, per Pin	±	±50		
T <sub>STG</sub>	Storage Temperature Range	-65	+150	°C	
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	260	°C
PD	Power Dissipation SOIC		-	1077	mW
		TSSOP	-	833	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage			6	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input or Output Voltage	0	V <sub>CC</sub>	V	
T <sub>A</sub>	Operating Temperature Range			+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Times	V <sub>CC</sub> = 2.0 V	-	1000	ns
		V <sub>CC</sub> = 4.5 V	-	500	
		V <sub>CC</sub> = 6.0 V	-	400	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC CHARACTERISTICS (Note 2)

				T <sub>A</sub> =	25°C	T <sub>A</sub> = −40°C to 85°C	T <sub>A</sub> = −55°C to 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Тур	G	Guaranteed Limits		Unit
V <sub>IH</sub>	Minimum HIGH Level Input		2.0	-	1.5	1.5	1.5	V
	Voltage		4.5	-	3.15	3.15	3.15	
			6.0	-	4.2	4.2	4.2	
V <sub>IL</sub>	Maximum LOW Level Input		2.0	-	0.5	0.5	0.5	V
	Voltage		4.5	-	1.35	1.35	1.35	
			6.0	-	1.8	1.8	1.8	
V <sub>OH</sub>	Minimum HIGH Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL},$	2.0	2.0	1.9	1.9	1.9	V
Voltage	$\label{eq:Voltage} \begin{array}{ l l l l l l l l l l l l l l l l l l l$	4.5	4.5	4.4	4.4	4.4		
			6.0	6.0	5.9	5.9	5.9	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 4.0 \text{ mA}$	4.5	4.2	3.98	3.84	3.70	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \leq 5.2 \text{ mA}$	6.0	5.7	5.48	5.34	5.20	
V <sub>OL</sub>	Maximum LOW Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL},$	2.0	0	0.1	0.1	0.1	V
	Voltage	I <sub>OUT</sub>   ≤ 20 μA	4.5	0	0.1	0.1	0.1	
			6.0	0	0.1	0.1	0.1	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 4.0 \text{ mA}$	4.5	0.2	0.26	0.33	0.4	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 5.2 \text{ mA}$	6.0	0.2	0.26	0.33	0.4	
I <sub>IN</sub>	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0	-	±0.1	±1.0	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ mA	6.0	-	2.0	20	40	μA

2. For a power supply of 5 V  $\pm$ 10% the worst-case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst-case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5 V and 4.5 V, respectively. (The V<sub>IH</sub> values at 5 V and 5.5 V are 3.5 V and 3.85 V, respectively.) The worst-case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occurs for CMOS at the higher voltage, so the 6.0 V values should be used.

AC CHARACTERISTICS (CL = 50 pF,  $t_r = t_f = 6$  ns (unless otherwise specified))

				T <sub>A</sub> =	25°C	T <sub>A</sub> = −40°C to 85°C	T <sub>A</sub> = −55°C to 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Тур	G	iuaranteed Li	mits	Unit
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay	C <sub>L</sub> = 15 pF, t <sub>R</sub> = t <sub>F</sub> = 6 ns	5.0	12	-	20	-	ns
t <sub>PHL</sub> , t <sub>PLH</sub>		C <sub>L</sub> = 50 pF,	2.0	60	120	151	179	ns
		t <sub>R</sub> = t <sub>F</sub> = 6 ns	4.5	12	24	30	36	
			6.0	10	20	26	30	
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Rise and Fall Time		2.0	30	75	95	110	ns
			4.5	8	15	19	22	
			6.0	7	13	16	19	
C <sub>PD</sub>	Power Dissipation Capacitance (per Gate) (Note 3)			25	-	-	-	pF
C <sub>IN</sub>	Maximum Input Capacitance			5	10	10	10	pF

3.  $C_{PD}$  determines the no-load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .

#### **MM74HC86**

#### **ORDERING INFORMATION**

Part Number	Marking	Package	Shipping <sup>†</sup>
MM74HC86M	HC86A	SOIC-14, Case 751A-03 (Pb-Free, Halide Free)	55 Units / Tube
MM74HC86MTC	HC 86A	TSSOP-14, Case 948G-01 (Pb-Free, Halide Free)	96 Units / Tube
MM74HC86MX	HC86A	SOIC-14, Case 751EF (Pb-Free, Halide Free)	2500 / Tape & Reel
MM74HC86MTCX	HC 86A	TSSOP-14, Case 948G-01 (Pb-Free, Halide Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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#### SOIC-14 CASE 751A-03 ISSUE L

#### DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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SOIC14 CASE 751EF **ISSUE O** DATE 30 SEP 2016 8.75 8.50 Α 0.65 7.62 14 8 14 8 В 4.00 6.00 5.60 3.80 ╞ 1.70 7 **PIN #1** 1,27 7 0.51 **IDENT.** 1.270.35 (0.33) $\oplus$  0.25 (M) С В Α LAND PATTERN RECOMMENDATION TOP VIEW 1.75 MAX 0.25 С 0.19 0.10 С 1.50 0.25 0.10 1.25 SIDE VIEW **FRONT VIEW** NOTES: A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C **B. ALL DIMENSIONS ARE IN MILLIMETERS** 0.50 0.25 × 45° C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS LAND PATTERN STANDARD: R0.10 GAGE D. SOIC127P600X145-14M PLANE R0.10 E. CONFORMS TO ASME Y14.5M, 2009 0.36 8° 0° 0.90 0.50 SEATING PLANE (1.04)DETAIL A SCALE 16 : 1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98AON13739G Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SOIC14 PAGE 1 OF 1

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